ASSP

ISO/IEC 18000-6 Type-C Compliant FRAM Embedded UHF Band RFID LSI *FerVID family*™

MB97R803A/B, MB97R804A/B

OVERVIEW

This specification defines the LSI specification for the passive RFID Tag LSI "MB97R803A/B, MB97R804A/B" based on international standard "EPCglobal Class 1 Generation 2 (Ver.1.2.0).

In this document, the term "interrogator" used in the EPCglobal standard is changed to R/W (reader/writer) in accordance with customary practice. The term "Tag" is used as it is.

■ FEATURE

- Compliant with EPCglobal Class 1 Generation 2 (C1G2) Ver.1.2.0
 - Compliant with all UHF bands all over the world (carrier frequency: 860 MHz to 960 MHz)
 - High-speed data transmission (compliant with EPCglobal C1G2)

 $R/W \rightarrow Tag: 26.7$ kbps to 128 kbps (when the counts of data 0 and 1are equal)

Tag \rightarrow R/W: 40 kbps to 640 kbps

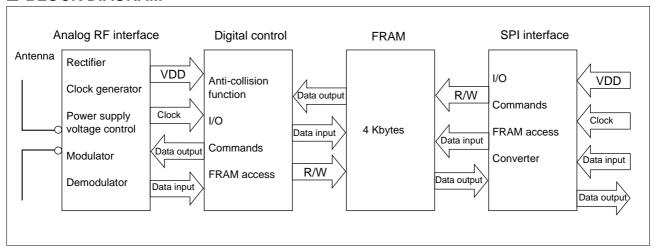
- DSB-ASK, SSB-ASK, PR-ASK modulation (compliant with EPCglobal C1G2)
- Anti-collision function
- Frequency Hopping
- BlockPermalock: User memory area can be locked from writing in unit of 1 block (16 bits).
- ReadLock (custom command): User memory area can be locked from reading in unit of 1 Area (256 bits)
- Serial Interface (SPI)
 - Accessible area: User memory area can be read/written through SPI.
 - Access control with RF interface is prioritized
 - Power supply: 2.3 V to 3.6 V (power is required for the memory access via SPI.)
 - Low power consumption : Operating current=70μA(Typ@2MHz),

Standby current=10µA(Typ)

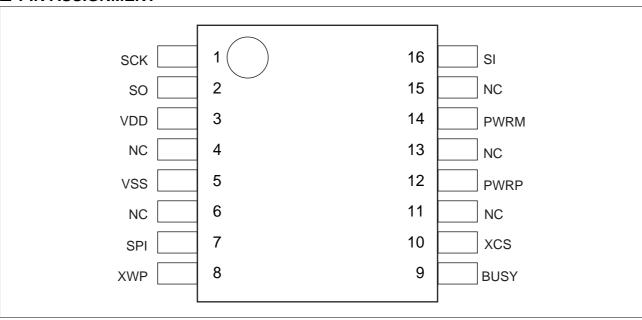
- Power down mode : Power down current =10nA(Typ)
- Package: 16-pin TSSOP (FPT-16P-M08)
- FRAM 4 Kbytes (4,096 bytes): High speed read/write Non-volatile memory
 - User Memory Area: 3,424 bytes
 - System Memory Area (including Reserved, EPC, and TID): 672 bytes
 - Read/Write Endurance: 1010 times
 - Memory Data Retention: 10years (+ 55 °C)



■ BLOCK DIAGRAM



■ PIN ASSIGNMENT



Pin Number	Pin Name	Interface	Function Description
12	PWRP	RF	Antenna pin
14	PWRM	RF	Antenna pin
9	BUSY	Serial	RF Interface Status pin
7	SPI	Serial	SPI Mode Switch pin
10	XCS	Serial	Chip Select pin
8	XWP	Serial	Write Protect pin
1	SCK	Serial	Serial Clock pin
16	SI	Serial	Serial Data Input pin
2	SO	Serial	Serial Data Output pin
3	VDD	Serial	Supply Voltage pin
5	VSS	Serial	Ground pin
4,6,11,13,15	NC	-	No Connection pin (There is no internal connection.)

■ RF INTERFACE

RF signal interface is compliant with EPCglobal C1G2 Ver.1.2.0 (as described in 6.3.1).

■ SERIAL INTERFACE

This LSI has SPI (Serial Peripheral Interface) interface. It is able to access FRAM User memory through the SPI interface. In this case, the external power supply is required.

1. Pin Function Description

The Serial Pin and its function descriptions are shown in the table below.

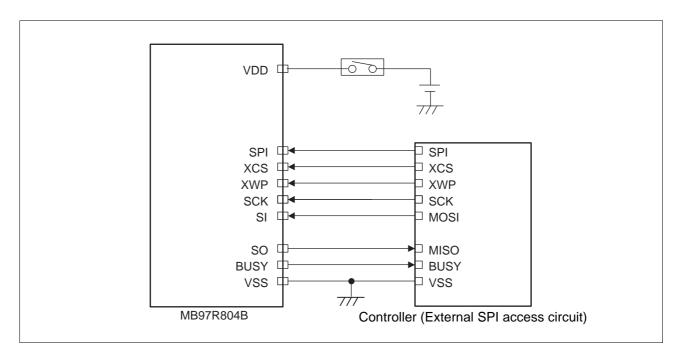
• Pin function

Pin Number	Pin Name	Function Description
9	BUSY	RF interface status pin When the VDD pin is set to ON during RF communication, BUSY will output "H". In this status, Serial communication will be ignored even if RF and Serial communications are both being performed at the same time, because the chip can only perform RF communication when BUSY outputs "H". Switching to the serial communication can be performed only when BUSY is "L".
7	SPI	SPI Mode Switch pin This is an input pin to control to switch to Serial communication mode. When SPI is "H", the LSI can be transfer to Serial communication mode.
10	xcs	Chip Select pin This is an input pin to select chip. When XCS is "H", device is deselect (standby status) as long as the LSI is not write status internally. And SO becomes High-Z. In this case, inputs from all pins other than the antenna pin are ignored. When XCS is "L", the chip will be in selected state (active). XCS must fall before inputting opcode.
8	XWP	Write Protect pin This is an input pin to protect FRAM from writing. When WXP is "L", FRAM memory is protected.
1	SCK	Serial Clock pin This is a clock input pin to input/output serial data. SI is loaded synchronously to a rising edge. SO is output synchronously to a falling edge.
16	SI	Serial Data Input pin This is an input pin of serial data. It inputs op-code, address, and writing data.
2	SO	Serial Data Output pin This is an output pin of serial data. Reading data of FRAM memory are output. Its High-Z during standby.
3	VDD	Supply Voltage pin: 2.3 V to 3.6 V
5	VSS	Ground pin

2. Connection to SPI Interface

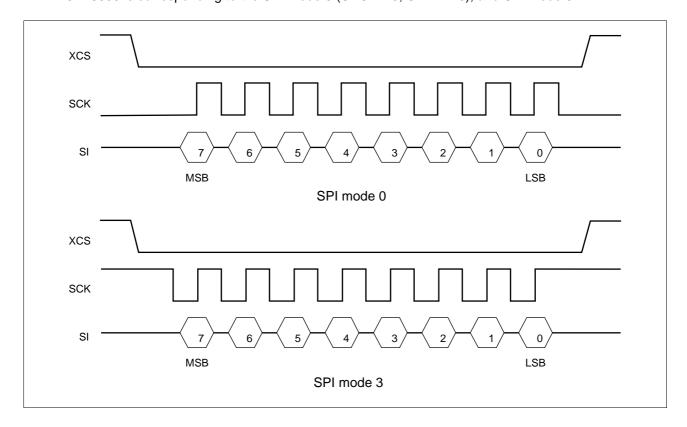
This LSI works as a slave of SPI. It can be connected to the microcontroller equipped with SPI port as shown in the figure below.

The external SPI controller shall monitor the BUSY signal. When BUSY signal is "H", the external power must be disconnected and the other signal must be "L".



3. SPI Mode

MB97R8030 is corresponding to the SPI mode 0 (CPOL = 0, CPHA = 0), and SPI mode 3.



4. Arbitration between RF and SPI communication

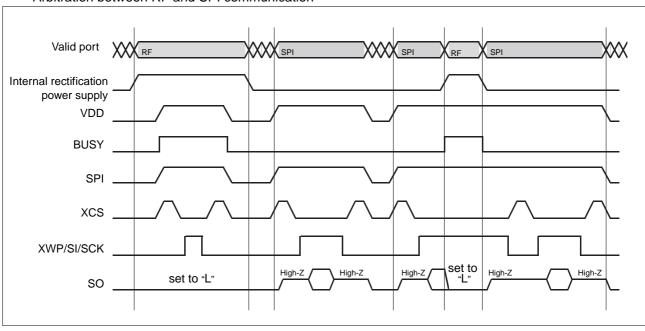
This LSI has access arbitration feature when there is access from both RF I/F and SPI I/F simultaneously. In this case, RF communication has priority.

BUSY signal indicates that there is access from RF I/F, and it is validated when VDD is connected.

The controller needs to confirm the BUSY signal before changing to the SPI communication mode. When the BUSY signal is in "H", the SPI communication is ignored if the SPI communication is performed at the same time because the LSI is executing RF communication.

The BUSY pin outputs "H" if the VDD pin is turned on during RF communication as the figure shown below.

• Arbitration between RF and SPI communication



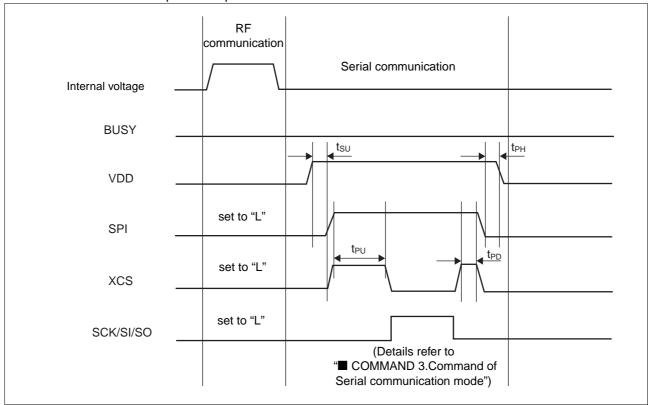
5. Power Sequence in Serial Communication Mode

The power sequence in Serial communication mode is shown in the figure below.

After asserting VDD, check that BUSY is "L" and then assert SPI and XCS at the same time. Wait for 1 ms or more after asserting XCS and then release XCS and begin Serial communication. The timing specifications for the power sequence are shown in the following table. Refer to "

COMMAND 3. Command of Serial communication mode" for details on the Serial communication timing specifications.

• Serial communication power sequence



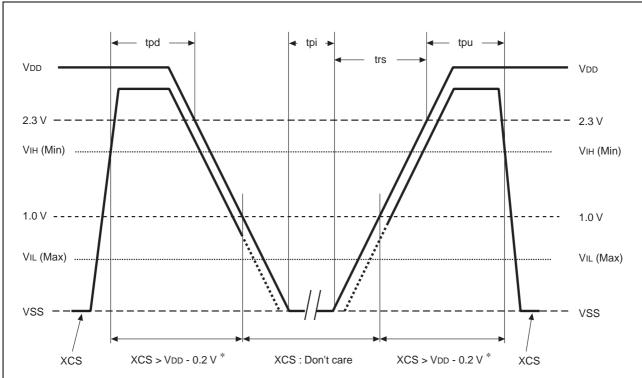
• Timing specifications during Serial communication

Parameter	Symbol	Value (Min)	Unit
SPI rising start time	t su	0	μs
Power supply hold time	tрн	0	μs
XCS level hold time at power ON	t PU	1000	μs
XCS level hold time at power OFF	t PD	0.06	μs

6. XCS Level Hold Time at Power ON/OFF

Power ON/OFF sequence while switching to the serial communication is shown in the figure below and XCS level hold time at power ON/OFF is shown in the table below.

• Power ON/OFF sequence in serial communication



*: XCS (Max)< VDD + 0.5 V

Note • Since power ON from middle-level may cause malfunction, VDD should rise from 0 V at power ON.

• If any operation other than the specified read cycle, write cycle or power ON/OFF sequence is performed, the stored data cannot be guaranteed.

Parameter	Symbol	Va	Unit	
Farameter	Symbol	Min	Max	Offic
XCS level hold time at power OFF	tpd	0.06	_	us
XCS level hold time at power ON	tpu	1000	_	us
Power supply falling time	tpi	10		ms
Power supply rising time	trs	0.05	200	ms

MEMORY

1. Memory addressing

(1) Memory addressing in RF communication mode

Memory addressing in RF communication mode use Extensible bit vectors (EBV) format, which is compliant with EPCglobal C1G2 Ver1.2.0 (Annex A).

(2) Memory addressing in Serial communication mode

The logical address is used for memory addressing in Serial communication mode.

2. Memory Map

(1) Memory area

The memory is divided into the following five areas.

Five memory areas

				Access command		
Name Memory size		BANK	Address range	RF communication	SPI communication	
User	$1712w \times 16b = 27,392bit$	11	000н to 06AFн	R/W/S/BLW/BLE	R/W	
TID	$16w \times 16b = 256bit$	10	000н to 00Fн	R/S	R	
EPC	$35w \times 16b = 560bit$	01	000н to 022н	R/W/S/BLW/BLE	R	
Reserved	$4w \times 16b = 64bit$	00	000н to 003н	R/W	_	
System	$14w \times 16b = 224bit$	_	_	L/BPL	*	

^{* :} Only lock and SPI error information can be read

Note: Command abbreviation:

R:READ, W: WRITE, S: SELECT, L: Lock, BPL: BlockPermalock, BLW: BlockWrite, BLE: BlockErase

The User, TID, EPC, and Reserved memory areas contain the data that is defined by the EPCglobal C1G2 specification (Chapter 6.3.2.1). The memory areas are also called as "Memory bank or "Bank" in EPC standard (In this specification, the User memory area is also called as "User memory").

In each memory bank, the logical address starts from zero (00H).

Logical addressing in EBV-8 format is used.

The system area stores user memory lock information and AreaGroup passwords.

The memory map is shown in shown in the table on next page. (The system area is not disclosed). The User memory consists of 7 Area Group and 107 Areas. The Area is defined as " 16×16 bits word" (256 bits)" of data and each AreaGroup contains several areas. The first 6 AreaGroup contain 16 areas, the last AreaGroup contains 11 areas.

In addition, the idea of "Bank" "Area" and "AreaGroup" shall be ignored when using the Serial communication mode.

Memory map

Bank	emory	Logical Address (RF communication)		Logical Address	Data Des	cription	otion Size (word)		Total	
	bank	(bit)	(word)	(SPI)		•	(word)	(word)	(bit)	
		00000н - 000FFн	0000н - 000Fн	0000н - 000Fн		Area00	16			
		00100н - 001FFн	0010н - 001Fн	0010н - 001Fн	A == = O == == 00	Area01	16	_		
		00200н - 00ЕFFн	0020н - 00ЕГн	0020н - 00ЕГн	- AreaGroup00	Area02 - 14	208			
		00F00н - 00FFFн	00F0н - 00FFн	00F0н - 00FFн	-	Area15	16			
Bank (RF communication) (word) (word)	0100н - 01FFн	AreaGroup01	Area00 - 15	256	4 740	27 202				
USER	11	02000н - 02FFFн	0200н - 02FFн	0200н - 02FFн	AreaGroup02	Area00 - 15	256	1,712	27,392	
		03000н - 03FFFн	0300н - 03FFн	0300н - 03FFн	AreaGroup03	Area00 - 15	256			
		04000н - 04FFFн	0400н - 04FFн	0400н - 04FFн	AreaGroup04	Area00 - 15	256			
		05000н - 05FFFн	0500н - 05FFн	0500н - 05FFн	AreaGroup05	Area00 - 15	256			
		06000н - 06АFFн	0600н - 06АГн	0600н - 06АГн	AreaGroup06	Area00 - 10	176			
		00000н - 0000Fн	0000н - 0000н	06С0н - 06С0н	StoredCRC16 (PC, EPC)	1			
		00010н - 0001Fн	0001н - 0001н	06С1н - 06С1н	StoredPC (Prot	ocol Control)	1			
EPC 1	00020н - 0020Fн	0002н - 0020н	06С2н - 06ЕОн	EPC		31	35	560		
			00210н - 0021Fн	0021н - 0021н	06Е1н - 06Е1н	XPC_W1		1		
		00220н - 0022Fн	0022н - 0022н	06Е2н - 06Е2н	XPC_W2	2				
TID	10	00000н - 000FFн	0000н - 000Fн	06F0н - 06FFн	TID		16	16	256	
		00010н - 0001Fн 0001н - 0001н		076Сн - 076Сн	KILL - Passwor	d[31:16]	1		64	
Re-	00			076Dн - 076Dн	KILL - Passwor	d[15:0]	1	4		
served	00	00020н - 0002Fн	0002н - 0002н	076Ен - 076Ен	ACCESS - Password[31:16]		1	4		
		00030н - 0003Fн	0003н - 0003н	076Fн - 076Fн	ACCESS - Pas					
Lock		_		06Е5н - 06Е5н			1	1	16	
				0778н - 0778н	AreaGroup00	Area00 - 15	1			
				0779н - 0779н	AreaGroup01	Area00 - 15	1			
				077Ан - 077Ан	AreaGroup02	Area00 - 15	00 - 10			
	ВЕК 111 00000н - 000FFн 00100н - 001FFн 00200н - 002FFн 00200н - 01FFFн 02000н - 02FFFн 02000н - 03FFFн 04000н - 04FFFн 06000н - 06AFFн 06000н - 060FFн 00210н - 0000Fн 00210н - 0021Fн 00220н - 0022Fн 00220н - 0022Fн 00000н - 0000Fh 00010н - 0000Fh 00010н - 0001Fh 00020н - 0000Fh 00010н - 0001Fh 00020н - 0002Fh 00030н - 0003Fh 00030н - 0003Fh 00030н - 0003Fh 00030н - 0003Fh 00030h - 0003Fh 00			077Вн - 077Вн	AreaGroup03	Area00 - 15	1	7	112	
				077Сн - 077Сн	AreaGroup04	Area00 - 15	1			
				077Dн - 077Dн	AreaGroup05	Area00 - 15	1			
				077Ен - 077Ен	AreaGroup06	Area00 - 10	1			
				0780н - 0780н		Area00	1			
				0781н - 0781н	AreaGroup00	Area01	1			
				0782н - 078Ен	Alcaoloupou	Area02 - 14	13			
				078Fн - 078Fн		Area15	1			
RPI				0790н - 079Fн	AreaGroup01	Area00- 15	16	107	1,712	
J, L				07А0н - 07АFн	AreaGroup02	Area00 - 15	16	107	1,114	
				07В0н - 07ВГн	AreaGroup03	Area00 - 15	16			
				07С0н - 07СГн	AreaGroup04	Area00 - 15	16			
	BPL			07D0н - 07DFн	AreaGroup05	Area00 - 15	16			
				07Е0н - 07ЕАн	AreaGroup06	Area00 - 10	11			

• TID

This LSI has a 96 bits TID that complies with EPC C1G2 standard. The TID consist of the 4 items shown in the following.

- An 8 bits data of EPC whose value is always "E2H"(bit89 to bit96)
- "A 12 bits IC manufacture code whose values is always "010H" (bit77 to bit88)
- Unique 60 bits serial number assigned by Fujitsu Semiconductor (bit17 to bit76)
- RFU 16 bits (bit1 to bit16)

Among the unique 60 bits serial number assigned by Fujitsu Semiconductor, the 8 bits from bit69 to bit76 define MB97R8030 code whose value is "03H". And 52 bits from bit17 to bit68 define chip information.

• TID configuration

MSB							L	.SB
96 8	9 88	7	7 76	69	68 17	16		1
EPC standa	d m	IC anufacture	:	"06н"	Chip information		RFU*	
"Е2н"	"Е2н" "010н"			unique serial number assigned by FUJITSU SEMICONDUCTOR				

*: Reserved for Future Use

· Notes on TID

TID has been written in FRAM during shipment test by the Fujitsu Semiconductor. However, FUJITSU SEMICONDUCTOR do not guarantee that the data written in FRAM before IR reflow is still retained after IR reflow. If this may cause problems, TID should be written by the customer after IR reflow.

■ FLAGS AND RANDOM NUMBER GENERATOR

The inventoried flag, selected flag, and random number generator are compliant with EPCglobal C1G2 Ver. 1.2.0. (Chapter 6.3.2.2, 6.3.2.3, 6.3.2.5)

■ TAG STATES AND SLOT COUNTER

The Tag states and slot counter are compliant with EPCglobal C1G2 Ver. 1.2.0. (Chapter 6.3.2.4)

■ COLLISION ARBITRATION ALGORITHM

The collision arbitration algorithm is compliant with EPCglobal C1G2 Ver. 1.2.0. (Chapter 6.3.2.6, 6.3.2.7, 6.3.2.8, 6.3.2.9)

■ COMMAND

1. Command of RF communication mode.

This LSI supports all mandatory commands and optional commands that defined by EPCglobal C1G2 Ver. 1.2.0. (Chapter 6.3.2.11). In addition, the ChgAreaGroupPwd and ReadLock is supported as custom command. The commands list and codes is shown in the table below.

For BlockWrite and BlockErase command (Optional command), parts of the specifications are different form the EPC C1G2 standard as described in "(1)BlockWrite (Optional command)" and "(2)BlockErase (Optional command)". ChgAreaGroupPwd and ReadLock command (Custom command) are described in "(4)ChgAreaGroupPwd (Custom command)" and "(5)ReadLock (Custom command)". Initialize command(Proprietary command) is described in "(6)Initialize(Proprietary command)".

• Command of RF communication mode

Items	Command	Code		
	QueryRep	00		
	ACK	01		
	Query	1000		
	QueryAdjust	1001		
	Slect	1010		
Mandatory	NAK	11000000		
	Req_RN	11000001		
	Read	11000010		
	Write	11000011		
	Kill	11000100		
	Lock	11000101		
	Access	11000110		
Optional	BlockWrite	11000111		
Ориона	BlockErase	11001000		
	BlockPermalock	11001001		
Custom	ChgAreaGroupPwd	111000000000100		
Cusion	ReadLock	111000000000111		
Proprietary	Initialize	1110000100001111		

Differences from EPCglobal C1G2 Ver. 1.2.0

• CRC-16

When the R/W writes the entire or part of the PC or EPC area of the Tag, CRC-16 stored in EPC memory 00_{H} to $0F_{\text{H}}$ of the Tag is disabled until an ACK command is received and a response that is not truncated (PC, EPC, CRC-16) is returned. After the completion of responding to ACK command, the correct CRC-16 value calculated during responding is written to EPC memory (00_{H} to $0F_{\text{H}}$) as well. If a truncated response to the ACK command is requested before CRC-16 is enabled, the CRC-16 value in the EPC memory, which has not been enabled, is returned as is.

• T4 time (time duration between commands sent by R/W)

The minimum value of T4 time is different from the value defined in EPC standards depending on the length of RTcal.

Length of RTcal	Minimum value of T4 time
44usec ≤ RTcal	2.0RTcal (EPC standards compliant)
22usec ≤ RTcal < 44usec	4.0RTcal
RTcal < 22usec	6.0RTcal

(1) BlockWrite (Optional command)

The following table shows the format of the BlockWrite command. Parts of the function of BlockWrite command are different form the EPCglobal C1G2 Ver.1.2.0 as following.

• MemBank : BlockWrite command can be executed in EPC and User memory bank. If BlockWrite command executed to the Reserved and TID bank, the LSI reply an error code.

• WordCount: If the WordCount is specified over 17 (11H), the LSI will reply an error code.

If part of the words to be written is locked by the BlockPermaLock, the LSI reply an error code.

• BlockWrite command

	Command	MemBank	WordPtr	WordCount	Data	RN	CRC-16
# of bits	16	2	EBV	8	WordCount × 16	16	16
Description	1100 0111	01: EPC 11: User	Starting Address Pointer	Number of word to write	Data to be written	Handle	

(2) BlockErase (Optional command)

The following table shows the format of the BlockErase command. Parts function of BlockErase command are different form the EPCglobal C1G2 Ver.1.2.0 as described as follows.

 MemBank : BlockErase command can be executed in EPC and User memory bank. If BlockErase executed to the Reserved and TID bank, the LSI reply an error code.

• WordCount: If the WordCount is specified over 17 (11H), this LSI will reply an error code.

If part of the words to be erased is locked by the BlockPermaLock, the LSI reply an error code.

• BlockErase command

	Command	MemBank	WordPtr	WordCount	RN	CRC-16
# of bits	16	2	EBV	8	16	16
Description	1100 1000	01: EPC 11: User	Starting Address Pointer	Number of word to erase	Handle	

(3) BlockPermaLock (Optional command)

This LSI, the unit of 1 Block is defined as 16 bits. The format of the BlockPermaLock command is shown in the table below. Parts function of the BlockPermaLock command are different form the EPCglobal C1G2 Ver.1.2.0 as described as follows.

- MemBank : BlockPermaLock command can be executed for User memory bank. If BlockPermaLock command executed to the EPC, Reserved and TID bank, the LSI reply an error code.
- BlockRange: If the BlockRange is specified over 17 (11H), the LSI reply an error code.

BlockPermaLock command

	Command	RFU	Read / Lock	MemBank	BlockPtr	Block Range	Mask	RN	CRC- 16
# of bits	16	8	1	2	EBV	8	Variable	16	16
Description	1100 1001	00н	0: Read 1: PermaLock	11:User	Mask starting address, specified in units of 16 blocks	Mask range, specified in units of 16 blocks	0: Retain current permalock setting 1: Assert permalock	Handle	

(4) ChgAreaGroupPwd (Custom command)

The following table "ChgAreaGroupPwd command" shows the format of the ChgAreaGroupPwd command. The R/W can use ChgAreaGroupPwd to change the password of each AreaGroup. To change the password of the AreaGroup, the R/W shall send the existing and new passwords. The initial password set as "0" at shipment stage from factory.

Only the tag in the secured or open state can execute the ChgBlockGroupPwd command.

ChgAreaGroupPwd has the following fields:

- AreaGroupPtr: This LSI has four 4 AreaGroup (01 to 03), which is specified with 2 bit value. 3 bit values
 from MSB shall be padded with Zero "0"
- Data: specifies the new password.
- · Passwd specifies the current password.

The ChgBlockGroupPwd command also includes the Tag handle and CRC-16. The CRC-16 is calculated over the first command code bit to the last handle bit.

If a Tag in the open or secured state receives ChgAreaGroupPwd with a valid CRC-16 but an invalid handle, it shall ignore the ChgAreaGroupPwd and remain in its current state. If the password set in the Passwd field does not correspond to the stored value, the new password is not written. The Tag will not reply and return to the arbitrate state.

A ChgAreaGroupPwd shall be prepended with a frame-sync.

After issuing ChgAreaGroupPwd, the R/W transmit CW for the lesser of Treply or 20 ms, where Treply is the time between the R/W's ChgAreaGroupPwd command and Tag's backscattered reply. The R/W may observe several possible incomes from a ChgAreaGroupPwd, depending on the success or failure of the Tag's password change operation.

- ChgBlockGroupPwd succeeds: After complete the ChgAreaGroupPwd, the Tag return the response shown
 in table "• Tag reply to ChgAreaGroupPwd command". The reply includes a header ("0" bit), Tag handle,
 and CRC-16 calculated over the "0" bit and handle. If the R/W observes this reply within 20 ms then the
 ChgAreaGroupPwd is completed successfully.
- The tag encounters an error: Tag returns an error code during the CW period rather than the reply shown in table "• Tag reply to ChgAreaGroupPwd command" (See "■COMMAND 4. Error of Serial communication mode" for the error code definition and reply format).
- Failure: If the R/W does not observe a reply within 20 ms then the ChgAreaGroupPwd does not complete successfully. The R/W may issue a Req_RN command (containing the Tag's handle) to verify that the tag is still in the R/W filed, and may reissue the ChgAreaGroupPwd.

Upon receiving a valid ChgAreaGroupPwd command, the Tag rewrites the AreaGroup password with the specified data. The new password is valid immediately after rewriting. The tag's reply to a ChgAreaGroupPwd use the extended preamble. (i.e., the Tag reply as if TRext = 1 regardless of the TRext value in the Query that initiated the round).

ChgAreaGroupPwd command

	Command	AreaGroupPtr	Data	Password	RN	CRC-16
# of bits	16	5	32	32	16	16
Description	1110 0000 0000 0100	AreaGroupPtr	New Passwd	Current Passwd	Handle	

• Tag reply to ChgAreaGroupPwd command

	Header	RN	CRC-16
# of bits	1	16	16
Description	0	Handle	

(5) ReadLock (Custom command)

This LSI has the ReadLock function. The ReadLock command specifies the ReadLock status in the unit of Area (256 bits). The format of ReadLock command is shown in table "• ReadLock command".

Only the tag in the secured or open state can execute the ReadLock command. ReadLock has the following fields:

- AreaGroupPtr : This LSI has four 4 AreaGroup (1 to 6), which is specified with 3 bit value. 2 bit values from MSB shall be padded with Zero "0".
- ReadLock contains a 32-bit payload defined as follows.
 - MASK0-15 0: Ignore the associated Action field and retain the current setting.
 - 1: Implement the associated Action field and overwrite the current ReadLock setting.
 - Action0-15 : Set the ReadLock status (1: Assert ReadLock, 0: Deassert ReadLock)
- Password: Set the corresponding password to the AreaGroup specified by the AreaGroupPtr. If the password is wrong, the ReadLock status can not be changed.

The AreaGroup6 does not contain Area 11 to Area 15, the setting toward these area is ignored.

The ReadLock command also includes the Tag handle and CRC-16. The CRC-16 is calculated over the first command code bit to the last handle bit.

If a Tag in the open or secured state receives ReadLock with a valid CRC-16 but an invalid handle, it shall ignore the ReadLock and remain in its current state.

A ReadLock shall be prepended with a frame-sync.

After issuing ReadLock, the R/W transmit CW for the lesser of Treply or 20 ms, where Treply is the time between the R/W's ReadLock command and Tag's backscattered reply. The R/W may observe several possible incomes from a ReadLock, depending on the success or failure of the Tag's memory lock operation.

• ReadLock succeeds : After complete the ReadLock, the Tag return the response shown in table

"• Tag reply to ReadLock command". The reply includes a header ("0" bit), Tag handle, and CRC-16 calculated over the "0" bit and handle. If the R/W observes this reply within 20 ms then the ReadLock is completed successfully.

• The tag encounters an error:Tag returns an error code during the CW period rather than the reply shown

in Table "• Tag reply to ReadLock command" (See "**ECOMMAND** 4. Error of Serial communication mode" for the error code definition and reply format).

• Failure : If the R/W does not observe a reply within 20 ms then the ReadLock does

not complete successfully. The R/W may issue a Req_RN command (containing the Tag's handle) to verify that the tag is still in the R/W filed, and

may reissue the ReadLock.

Upon receiving a valid ReadLock command, the Tag perform the lock operation.

The tag's reply to a ReadLock use the extended preamble. (i.e., the Tag reply as if TRext = 1 regardless of the TRext value in the Query that initiated the round).

ReadLock command

	Command	AreaGroupPtr	Payload	Password	RN	CRC-16
# of bits	16	5	32	32	16	16
Description	1110 0000 0000 0111	AreaGroupPtr	Mask/Action (See the table below)	32 bit password	Handle	

ReadLock command payload

											F	Pay	loa	d														
							MA	SK												Act	ion							
0	0 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15								15	0	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15			

Tag reply to ReadLock command

	Header	RN	CRC-16
# of bits	1	16	16
Description	0	Handle	

(6) Initialize (Proprietary command)

The following table shows the format of the Initialize command. This command is provided for manufacturer to initialize the memory area excepting TID bank and part of system area after the IR reflow during tag assembly process. Data area and Lock information area are overwriten with data zero(0) and disabled to be intialized again. Once this command is executed, the System Lock status becomes to be Normal.

Initialize command shall be prepended with a frame-sync. Return link frequency is specified by Query command issued previously.

Initialize command can be executed from all the state excepting Kill state, and no tag is idetified by inventory sequence. Therefore it is not allowed to execute Initialize command if multiple tags are existed in the RF communication fields of reader/writer.

The command sequence is described as following.

- 1. R/W issues Query, in which DR value and M value specifies return link frequency.
- 2. R/W issues initialize command. Data field in the command has to be " 00h".
- 3. Tag confirms CRC16. If the CRC16 is invalid, tag ignores the command.
- 4. If SYSLOCK information is NORMAL or KILL, tag ignores the commad.
- 5. The memory area excepting TID bank and part of system area is initialized (data zero(0) is overwritten.)
- 6. NOMAL value is stored in SYSLOCK information.
- 7. Tag responds to the command as shown in the following table.

Initialize command

	Command	Data	CRC-16
# of bits	16	8	16
Description	1110 0001 0000 1111	00H	

· Tag reply to Initialize command

	Header	CRC-16
# of bits	1	16
Description	0	

2. Error code of RF communication mode

The error code is compliant with EPCglobal C1G2 Ver. 1.2.0 (Annex I).

3. Command of Serial communication mode

This LSI accepts 2 commands specified in Op-code. Op-code is an 8 bits code as shown in the table below. If other codes are inputted, the command is ignored. If XCS is risen during the input sequence of Op-code, the command cant be executed.

Op-code of Serial interface

Name	Function	Op-code
READ	Read from memory area in unit of 16 bits	0000 0011
WRITE	Write to memory area in unit of 16 bits	0000 0010

(1) READ

The READ command is executed in units of 16 bits (1 word).

The memory addressing is described as table "■MEMORY 2. Memory map • Memory map". The sequence of READ command is shown in the figure below.

Op-code and 16 bits address are input through SI. synchronously to the rising edge of SCK.

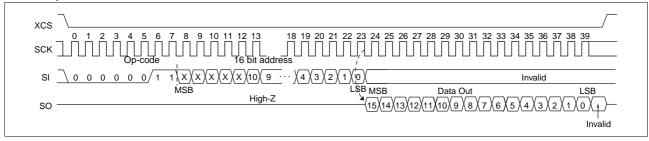
The upper 5 address bits don't care. Then, the data is read through SO synchronously to the falling edge of SCK.

During the data is read, the SI value is invalid. The reading address is automatically incremented by each 16-cycle clock input until XCS is rising. If the most significant address is reached, the counter rolls over to "0000H".

The rising edge of XCS terminate the READ operation.

The READ command can be executed in the User memory, TID, EPC, and Lock status areas. If the specified areas are in Read Locked, "0000н" is output instead of the data. If this LSI is in Kill status, the READ command is ignored.

· Sequence of READ command.



(2) WRITE

The WRITE command is executed in units of 16 bits (1 word). The memory addressing is described as table "■ MEMORY 2. Memory map • Memory map".

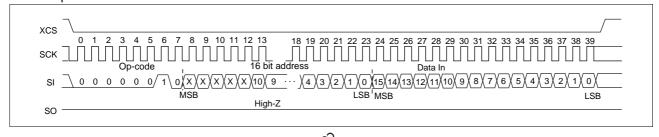
The sequence of WRITE command is shown in the figure below.

Op-code, 16 bits address and 16 bits of writing data are input through SI synchronously to the rising edge of SCK.

The upper 5 address bits don't care. The writing address is automatically incremented by the following 16 bits data input until XCS is rising. If the most significant address is reached, the counter rolls over to "0000H". The rising edge of XCS terminate the write operation.

The WRITE command can be executed in the User memory areas. It writes error information to the SPI Error Information Register. (The error code is described in " ■COMMAND 4. Error of Serial communication mode") If this LSI is in Kill status, the WRITE command is ignored.

Sequence of WRITE command



4. Error of Serial Communication Mode

In Serial communication mode, if the LSI encounters an error when executing a READ/WRITE command, the error codes will be stored in the SPI Error Information Register.

When reading error occurred, "0000H" is output instead of the data. When writing error occurred.

• SPI Error Information Register

The following table shows the format of error information that stored in the SPI Error Information Register (SPI_ERR_Info:address = 8000H, see table "■MEMORY 2. Memory map • Memory map"). The information can be read by the READ command. If the start bit of addresses for the following command is "0", the error information register will be cleared after an error occurs.

• SPI Error Information Register format

Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Function	0	0	0	0	0	0	0	0	0	0	0	0		ERR	OR*	

*: ERROR

b1000 : Low voltage detection

b0100 : Write NG b0010 : Read NG

b0001 : NG because RF occurred b0000 : Finished successfully

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Rating

Parameter	Symbol		Rating		Unit	Remarks
Parameter	Symbol	Min	Тур	Max	Offic	Remarks
Maximum input voltage	Vmax	_	_	3.0	V	Between PWRP-PWRM
Power supply voltage	V _{DD}	- 0.5		+ 4.0	V	
Input voltage	VIN	- 0.5		V _{DD} + 0.5	V	
Output voltage	Vоит	- 0.5	_	V _{DD} + 0.5	V	
ESD voltage immunity	VESD	- 2	_	+ 2	kV	Human Body Model
CSD voltage illillullity	VESD	- 100		+ 100	V	Machine Model
Storage temperature	Tstg	- 40		+ 85	°C	Excluding FRAM data retention guarantee

WARNING: Semiconductor devices may be permanently damaged by application of stress (including, without limitation, voltage, current or temperature) in excess of absolute maximum ratings.

Do not exceed any of these ratings.

2. Recommended Operation Conditions

	arameter			Value		Unit	Remarks
	arameter	Symbol	Min	Тур	Max	Onit	Remarks
Operating junction temperature	on	Tj	-20	_	+85	°C	
Retention guara temperature	ntee	Trtn1	-20	_	+55	°C	Retention guarantee period: 10years
	Antenna input frequency	Fclk	860	_	960	MHz	According to the Radio Law
	Reception modulation depth	(A-B)/A	80	90	100	%	
RF	Receiving bit rate	F_fwd	26.7		128	kbps	PIE code: mark rate = 1/2
communication	Receiving waveform rise time	Tr	1		500	μs	
	Receiving waveform settling time	Ts	_	_	1500	μs	
	Receiving waveform fall time	Tf	1		500	μs	
	Power supply voltage	V _{DD}	2.3	3.3	3.6	V	
Serial communication	"H" level input voltage	Vін	V _{DD} - 0.2		V _{DD} + 0.3	V	
	"L"level input voltage	VIL	- 0.3		+ 0.4	V	

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated under these conditions.

Any use of semiconductor devices will be under their recommended operating condition. Operation under any conditions other than these conditions may adversely affect reliability of device and could result in device failure.

No warranty is made with respect to any use, operating conditions or combinations not represented on this data sheet. If you are considering application under any conditions other than listed herein, please contact sales representatives beforehand.

3. RF Communication Characteristics

Par	ameter	Symbol		Value	!	Unit	Conditionas/Remarks
Fai	ameter	Symbol	Min	Тур	Max		Conditionas/Remarks
Minimum oper when reading	ating power	P _{R_MIN}	_	-6	_	dBm	Measured for TSSOP16 PKG Tari=25us, RTcal=3Tari,TRcal=2.6RTcal,
Minimum operating power when writing		Pw_min	_	-6	_	dBm	DR=8,FM0,BLF=41kbps, DSB-ASK, Modulation depth=90%*
Maximum ope	rating power	Рмах		18		dBm	
MB97R803A	Equivalent input capacitance	СР	_	0.47	_	pF	Input power = -6dBm, paralel model (At 953MHz)
(Wafer)	Equivalent input resistance	R₽		2	_	ΚΩ	Input power = -6dBm, paralel model (At 953MHz)
MB97R804B	Equivalent input capacitance	СР	_	0.69		pF	Input power = -6dBm, paralel model (At 953MHz)
(TSSOP)	Equivalent input resistance	R₽	_	1.7	_	ΚΩ	Input power = -6dBm, paralel model (At 953MHz)
Returning bit rate		F_rtrn	40		640	kbps	
Error of returning bit rate		Ftolerance	± 5		± 22	%	
Bit rate change during returning		Fvariation	-21		14	%	This is different from the value defined in EPC standards.

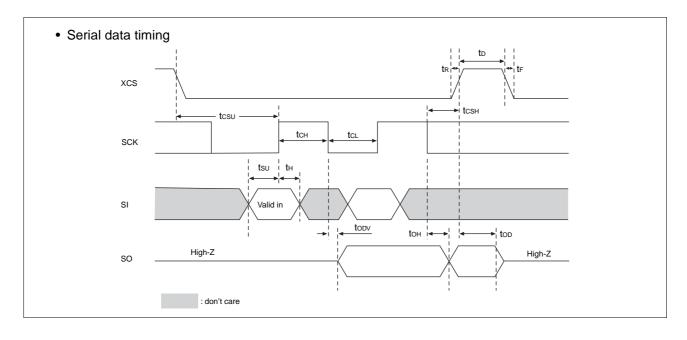
^{*:} These characteristics are the values for the standalone LSI, and do not specify the values when the LSI is connected to other circuits such as a microcomputer.

4. Serial Communication DC Characteristics

4. Serial Communication DC Characteristics								
Parameter		Symbol	Value			Unit	Remarks	
		Symbol	Min	Тур	Max	Oilit	Remarks	
Input leakage current		Iu	_	_	± 5	μΑ	VIN = 0V to VDD	
Output leakage current		ILO	_	_	± 5	μА	$V_{OUT} = 0V$ to V_{DD} , when output pin is Hi-Z	
Power supply	Operating current	Icc	_	70	200	μΑ	SCK = 2MHz, Vdd=3.0V	
	Power down current 1	I _{PD1}	_	0.01	5	μА	SPI = 0V or open XCS, XWP, SCK, SI = 0V or VDD No RF reception	
	Power down current 2	I _{PD2}	_	3	5	uA	SPI = 0V or open XCS, XWP, SCK, SI = 0V or V _{DD} RF receiving	
	Standby current	IsB	_	10	50	μА	SPI = VDD XCS, XWP, SCK, SI = 0V or VDD	
Output voltage at "H" level		Vон	V _{DD} × 0.8	_	V _{DD}	V	Іон = −1mA	
Output voltage at "L" level		Vol	0		0.4	V	IoL = 2mA	
SPI pin pull-down resistance		Rın	0.8	1	1.2	МΩ	VIN = VDD	

5. Serial Communication AC Characteristics

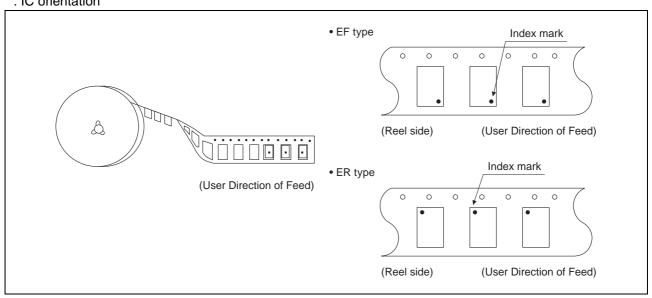
Donomotor	Cymahal	Va	I I m i f	
Parameter	Symbol	Min	Max	Unit
SCK clock frequency	fск	_	2	MHz
Clock high time	tсн	200	_	ns
Clock low time	t c∟	30	_	ns
Chip select set time	t csu	10	_	ns
Chip select hold time	tсsн	10	_	ns
Output disable time	top		20	ns
Output data valid time	todv		35	ns
Output hold time	tон	0	_	ns
Deselect time	to	200	_	ns
Data rise time	t _R		50	ns
Data fall time	t⊧	_	50	ns
Data set up time	t su	10	_	ns
Data hold time	tн	10	_	ns



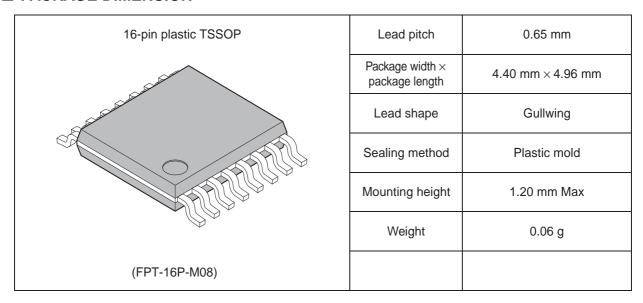
■ ORDERING INFORMATION

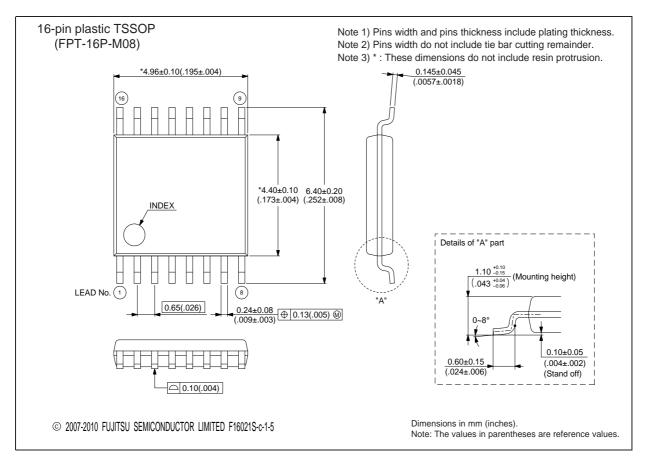
Part number	Interface	Shipping method	Wafer thickness	Remarks
MB97R803A-DIAP15	RF	Wafer (After dicing)	150 μm ± 25.4 μm	
MB97R804BPFT-G-JNEFE1	RF + SPI	TSSOP16		EF type*
MB97R804BPFT-G-JNERE1	IXI + SFI	(Tape & Reel)		ER type*

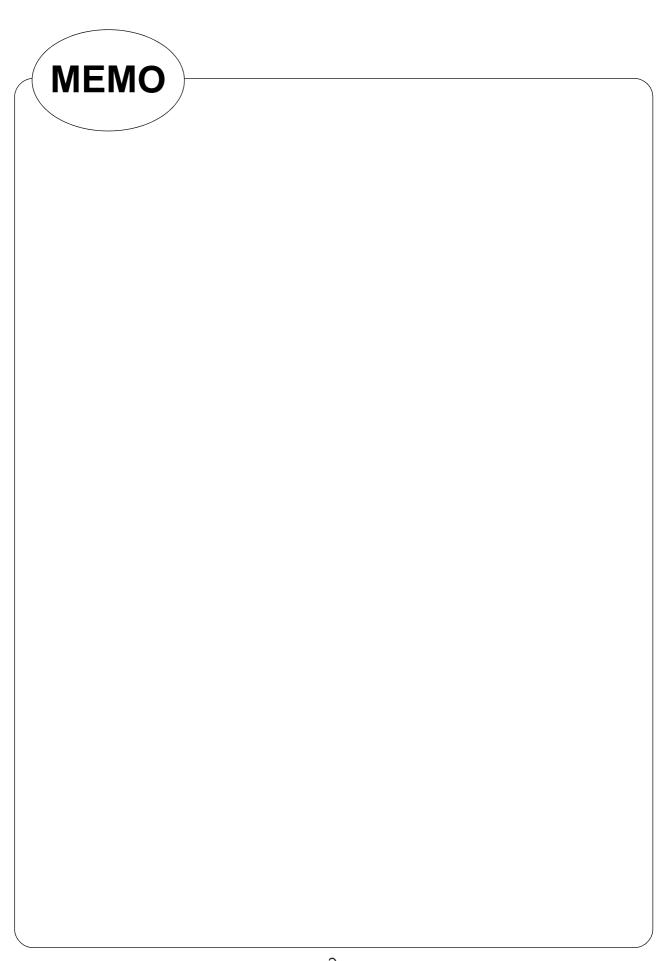
*: IC orientation



■ PACKAGE DIMENSION







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